# **CPI Electron Device Business - Microwave Power Module**

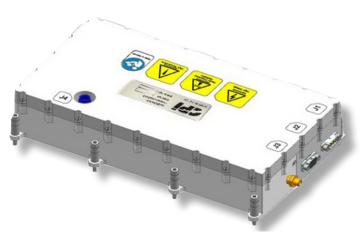
The PTXM1069 is an ultra compact modular microwave power module with an integrated "super mini" travelling wave tube (TWT), a solid state preamplifier, and an optimized high density switch mode power supply.

The PTXM1069 features a broadband (6.0 to 18.0 GHz) TWT capable of providing over 140 W.

The MPM can be configured to incorporate a variety of TWT models, allowing the user to specify frequency and peak power parameters.

The MPM includes a high-speed focus electrode modulator to permit operation at high PRFs. This makes the MPM ideal for pulsed applications such as Electronic Countermeasure (ECM) and radars.

To learn more about CPI EDB's MPM capabilities, contact CPI EDB at ElectronDevices@cpi-edb.com or call us at +44 (0)20 8573 5555



The PTXM1069 is an ultra-compact modular microwave power module with an integrated "super mini" travelling wave tube (TWT)

### FEATURES:

- Frequncy: 6.0 18.0 GHz
- Duty cycle: 100% max
- Weight: 5.3 lbs (2.4 kgs) max
- Pulsewidth: 0.1 to ∞µs

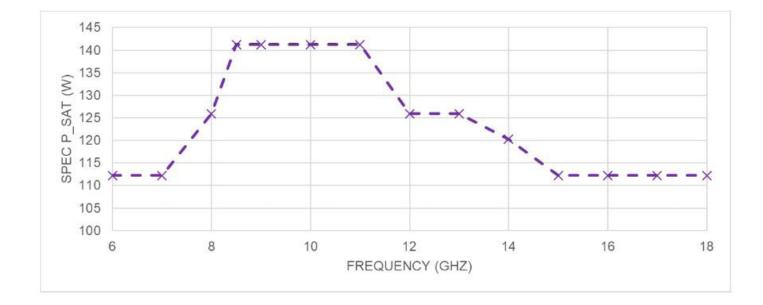
#### BENEFITS

- Compact and lightweight
- Excellent thermal management
- High electrical efficiency
- High-voltage capability
- Suitable for high-altitude operations
- Resilient in high-humidity environments

### **APPLICATIONS**:

- Radar systems
- Electronic Countermeasure (ECM) systems





## **RF Characteristics**

Frequency range			See graph
RF output power			See graph
(saturated)			
Duty cycle			100 % max
Small signal gain			55 dB nom
RF input power			0 ± 1 dBm
(for saturation)			
Second harmonic at	saturatio	n	
	6.0 - 7.0 0	GHz:	-3 dBc
	8.0- 9.0 G	Hz:	-6 dBc
	>9 GHz:		-8 dBc
Noise power density	y .	-24 dB	m/MHz max
(Beam On)			
Noise Power Densit	y	-75 dB	m/MHz max
(Beam Off)			
Maximum spurious	PM	-38 (	dBc45 dBc
measured in a 100 H	łz		
bandwidth Note 1			

Phase noise power density		
-100 dBc/Hz max at 1 kHz from carrier		
-110 dBc/Hz max at 10 kHz from carrier		
-120 dBc/Hz max at >100 kHz from carrier		
Noise figure	27 dB (typical)	
Input VSWR	2.0:1 max	
Output VSWR	2.0:1 max (No damage)	
Pulse width	0.1 to ∞µs (CW Operation)	
Pulse delay (ON	150 ns max	
command to RF Out)		
Pulse repetition	20 kHz max	
frequency (PRF)		

# **Prime Power Requirements**

Power consump	tion 620 W maximum
	(±10% normal operating range)
Prime power	270 V DC Per MIL-STD-704E

Notes: 1 Other characteristics are available to special

order



Connectors	
Primary power input	Glenair: MRM18396
connector	
Control and monitorin	ng Glenair: MRM18395
connector	
RF input connector	SMA female
RF output connector	TNC female
Control and Monitorir	ng
Control inputs	HV on,
	TWT beam on
Status outputs	Standby,
	HV on,
	Fault
Fault protection	
Extensive internal BIT	incorporated to monitor
most TWT parameters	s. MPM shuts down under
fault conditions. TWT	operating parameters can
be monitored externa	ally to aid fault location.
An over-temperature	trip is incorporated.
Fault outputs	Over-temperature
	summary fault
TWT monitor outputs	Cathode voltage,
	Beam current,
	Helix current
Heater warmup	180 seconds from power on
Automatic restart	Auto-reset after fault is
	included (3 restarts)

## **Mechanical** Mechanical outline 254.0 x 155.0 x 45.5 mm including fixings 1V020806 Mechanical outline drawing 5.3 lbs (2.4 kgs) max Weight Orientation Any Finish Nickel plated Markings/Labels Type number Model number Serial number **Connector ident** Hazard warning Cooling Conduction via baseplate,

# Options (available on request)

Alternative prime power 28 V, 115 VAC 3-phase (plug-in or stand-alone converters)

+71 °C maximum temperature

## Environmental

Temperature		-40 °C to + 71 °C
(operating)		
Ambient temperature		-54 °C to + 100 °C
(storage)		
Baseplate tempera	ture	+71 °C maximum
(MPM)	colle	ector hotspot (operating)



Altitude (operating)	0 - 40,000 ft
Vibration	0.2 g <sup>2</sup> /Hz 10 to 40 Hz
(operating - 3 axes)	0.04 g <sup>2</sup> /Hz 40 to 2000 Hz
Shock (3 axes)	40 g, 6 ms half sine
Humidity	MIL-STD-810D
(95 % RH non-condensi	ng) Method 507.2
	procedure II



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For more detailed information, please refer to the corresponding technical description if one has been published, or contact CPITMD Technologies. Specifications may change without notice as a result of additional data or product refinement. Please contact CPI TMD Technologies before using this information for system design.